GigaDevice Semiconductor Inc.

Migration from GD32E230 series to GD32E235 series

Application Note AN169

Revision 1.0

(Aug.2024)



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1. Introduction

The GD32E235xx device is a new 32-bit general-purpose microcontroller based on the ARM® Cortex®-M23 core. It has very high resource similarity with the GD32E230xx series, and this application note aims to help you quickly port applications from the GD32E230xx series microcontroller to the GD32E235xx series microcontroller.

In order to make better use of the information in this application note, you need to download it from the website www.GD32MCU.com, such as datasheet, user manual, official code and various development tools.



2. Introduction to hardware differences

The definition of pins for GD32E235xx series chips and GD32E230xx series devices in the same packaging is completely the same.



3. Comparison of resource and peripheral

The internal resources of GD32E235xx and GD32E230xx devices with the same suffix are consistent. In addition, GD32E235 has added a chip model with a FLASH capacity of 128KB and a RAM capacity of 16KB: GD32E235xB. As shown in <u>Table 3-1. GD32E235xB devices</u> features and peripheral list.

Table 3-1. GD32E235xB devices features and peripheral list

Part Number		GD32E235xx								
		KBU6	КВТ6	СВТ6						
	FLASH(KB)	128 ⁽¹⁾	128 ⁽¹⁾	128 ⁽¹⁾						
SRAM(KB)		16 ⁽¹⁾	16 ⁽¹⁾	16 ⁽¹⁾						
	General	5	5	5						
	timer(16bit)	(2, 13-16)	(2, 13-16)	(2, 13-16)						
	Advanced	1	1	1						
ဟု	timer(16bit)	(0)	(0)	(0)						
Timers	SysTick	1	1	1						
-	Basic	1	1	1						
	timer(16bit)	(5)	(5)	(5)						
	Watchdog	2	2	2						
	RTC	1	1	1						
	USART	2	2	2						
<u>.</u>		(0-1)	(0-1)	(0-1)						
ctiv	I2C	2	2	2						
Connectivity		(0-1)	(0-1)	(0-1)						
ŏ	SPI/I2S	2/1	2/1	2/1						
		(0-1)/(0)	(0-1)/(0)	(0-1)/(0)						
	GPIO	27	25	39						
CMP		1	1	1						
	EXTI	16	16	16						
	Units	1	1	1						
	Channels	10	10	10						
ADC	(External)									
	Channels	2	2	2						
	(Internal)									
	Package	QFN32	LQFP32	LQFP48						

Note: (1) Compared with GD32E230x8 devices with the same packaging, these three new devices have the same resources except for the difference in FLASH capacity and SRAM capacity.



4. Program Migration

4.1 Differences in FMC

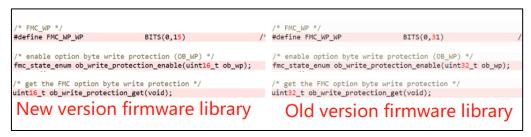
From the previous section, it can be seen that the FLASH capacity of GD32E235xB is larger, and there is a difference in the number of bits in the write protect register (FMC_WP) between GD32E235xx and GD32E230xx devices. As shown in Figure 4-1. Comparison of Write Protect Registers (FMC WP) Differences between GD32E230xx and GD32E235xx devices.

Figure 4- 1. Comparison of Write Protect Registers (FMC_WP) Differences between GD32E230xx and GD32E235xx devices



The new version firmware library GD32E23x_Firmware_Library(Version 2.0.0 and above) has made modifications to the "gd32e23x_fmc.h" and "gd32e23x_fmc.c" documents in order to be compatible with GD32E235xB. As shown in *Figure 4-2. The difference of "gd32e23x fmc. h" document*. The detailed functions can be found in the "gd32e23x_fmc. c" document.

Figure 4- 2. The difference of "gd32e23x_fmc. h" document



GD32E230 series ported to GD32E235 series

When porting from GD32E230xx to GD32E235xx or from GD32E235xx to GD32E230xx, it is necessary to pay attention to whether the flash size is compatible and modify the two documents "gd32e23x_fmc. h" and "gd32e23x_fmc. c". When replacing chips with flash capacities below 128KB, if the files "gd32e23x_fmc. h" and "gd32e23x_fmc. c" are not modified, it will not affect the functionality of the chip.

4.2 Differences in Comparator

The hysteresis levels of the GD32E235xx series and GD32E230xx series comparators can be configured, but the GD32E235xx series cannot be configured as high hysteresis mode. If the GD32E235xx comparator operates in high hysteresis mode, it will result in functional errors with incorrect comparator results, When porting from GD32E230xx to GD32E235xx, this issue needs to be noted.

Figure 4- 3. The GD32E233xx series comparator can be configured in high hysteresis mode, while the GD32E235xx series comparator cannot be configured in high hysteresis mode

11.4.1.		Control/status register (CMP_CS)														
Address offset: 0x				et: 0x0	00											
Reset value: 0x000																
		This register has to be accessed by word (32-bit)														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16	
							Rese	erved					•			
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0	
CMPLK	CMPO	CMPH	ST[1:0]	CMPPL	. CMPOSEL[2:0]			Reserved	C	MPMSEL[2	:0]	CMP	M[1:0]	CMPSW	CMPEN	
rwo	r	rv	w/r	rw/r		rwir				rw/r		n	w'r	rwir	rwr	
Bits		Fields			Descri	ptions										
31:16		Reserv	ed		Must be	e kept a	t reset v	/alue								
15		CMPLK CMP lock														
					This bit could set all control bits of CMP as read-only. This bit is write-once. It can											
					only be cleared by a system reset once It is set by software.											
					0: CMP_CS[15:0] bits are read-write											
					1: CMP	_CS[15	:0] bits	are read	l-only							
14		CMPO CMP output														
		This is a copy of CMP output state, which is read only.														
		0: Non-inverting input be							input below inverting input and the output is low							
				1: Non-inverting input above inverting input and the output is high												
13:12	13:12 CMPHST[1:0] CMP hysteresis															
					These bits are used to control the hysteresis level.											
				00: No hysteresis												
					01: Low hysteresis											
				_	10: Medium hysteresis											
					11: High hysteresis											



5. Revision history

Table 5-1. Revision history

Revision No.	Description	Date
1.0	Initial Release	Aug.8 2023
1 1	Explanation of adding differences in	Aug.5 2024
1.1	the comparator	Aug.5 2024



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